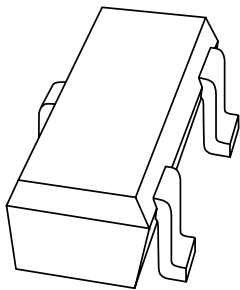


# DATA SHEET



**2PB709AW**

**PNP general purpose transistor**

Product data sheet

2002 Jun 26

## PNP general purpose transistor

2PB709AW

## FEATURES

- High collector current (max. 100 mA)
- Low collector-emitter saturation voltage (max. 500 mV).

## APPLICATIONS

- General purpose switching and amplification.

## DESCRIPTION

PNP transistor in an SC-70 (SOT323) plastic package.  
NPN complement: 2PD601AW

## MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>
2PB709AQW	N5*
2PB709ARW	N7*
2PB709ASW	N9*

## Note

1. \* = p: made in Hong Kong.  
\* = t: made in Malaysia.

## PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector

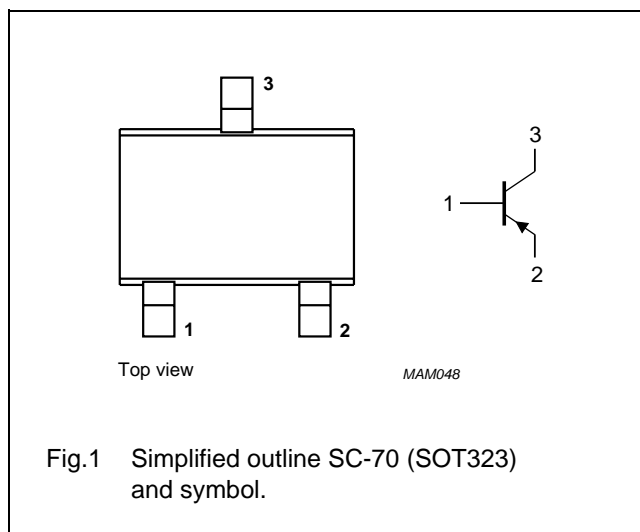


Fig.1 Simplified outline SC-70 (SOT323) and symbol.

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–45	V
$V_{CEO}$	collector-emitter voltage	open base	–	–45	V
$V_{EBO}$	emitter-base voltage	open collector	–	–6	V
$I_C$	collector current (DC)		–	–100	mA
$I_{CM}$	peak collector current		–	–200	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$ ; note 1	–	200	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

## Note

1. For mounting conditions, see “Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18”.

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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	625	K/W

## Note

- For mounting conditions, see “Thermal considerations and footprint design for SOT323 in the General Part of Data Handbook SC18”.

## CHARACTERISTICS

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{CBO}$	collector-base cut-off current	$I_E = 0$ ; $V_{CB} = -45\text{ V}$	–	–10	nA
		$I_E = 0$ ; $V_{CB} = -45\text{ V}$ ; $T_j = 150\text{ °C}$	–	–5	μA
$I_{EBO}$	emitter-base cut-off current	$I_C = 0$ ; $V_{EB} = -5\text{ V}$	–	–10	nA
$h_{FE}$	DC current gain	$I_C = -2\text{ mA}$ ; $V_{CE} = -10\text{ V}$			
	2PB709AQW		160	260	
	2PB709ARW		210	340	
	2PB709ASW		290	460	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -100\text{ mA}$ ; $I_B = -10\text{ mA}$ ; note 1	–	–500	mV
$C_c$	collector capacitance	$I_E = I_E = 0$ ; $V_{CB} = -10\text{ V}$ ; $f = 1\text{ MHz}$	–	5	pF
$f_T$	transition frequency	$I_C = -1\text{ mA}$ ; $V_{CE} = -10\text{ V}$ ; $f = 100\text{ MHz}$			
	2PB709AQW		60	–	MHz
	2PB709ARW		70	–	MHz
	2PB709ASW		80	–	MHz

## Note

- Pulse test:  $t_p \leq 300\text{ μs}$ ;  $\delta \leq 0.02$ .

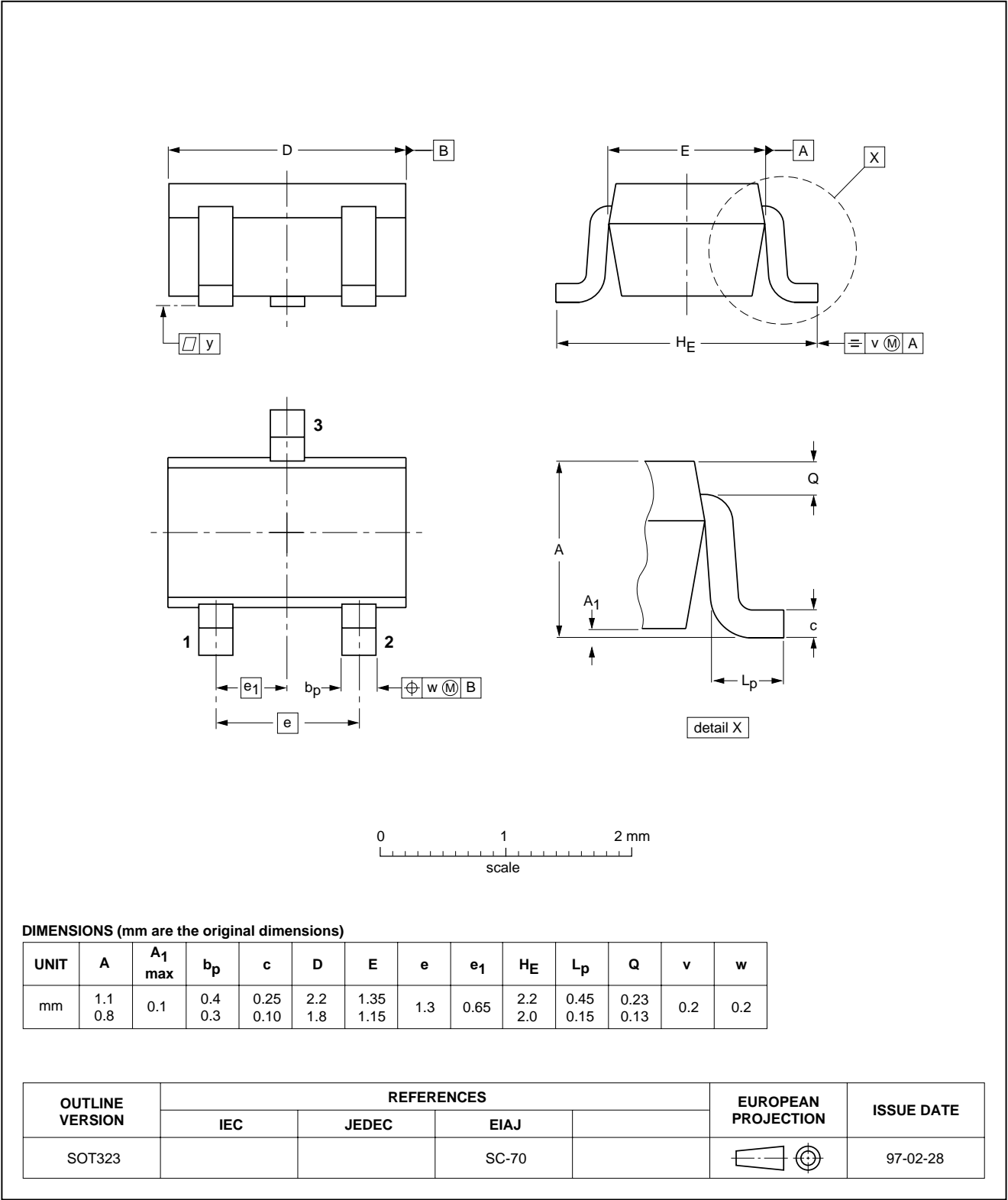
PNP general purpose transistor

2PB709AW

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT323



## PNP general purpose transistor

2PB709AW

## DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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